TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

## 2SA1015

AUDIO FREQUENCY GENERAL PURPOSE AMPLIFIER APPLICATIONS DRIVER STAGE AMPLIFIER APPLICATIONS

- High Voltage and High Current.
: $\mathrm{V}_{\mathrm{CEO}}=-50 \mathrm{~V}$ (Min.), $\mathrm{I}_{\mathrm{C}}=-150 \mathrm{~mA}$ (Max.)
- Excellent hFE Linearity
: $\mathrm{hFE}_{\mathrm{F}}(2)=80$ (Typ.) at $\mathrm{V}_{\mathrm{CE}}=-6 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-150 \mathrm{~mA}$
$: h_{F E}\left(I_{C}=-0.1 \mathrm{~mA}\right) / h_{F E}\left(\mathrm{I}_{\mathrm{C}}=-2 \mathrm{~mA}\right)=0.95(\mathrm{Typ}$.
- Low Noise : $\mathrm{NF}=1 \mathrm{~dB}$ (Typ.) at $\mathrm{f}=1 \mathrm{kHz}$
- Complementary to 2 SC 1815 .

MAXIMUM RATINGS $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
| :--- | :---: | :---: | :---: |
| Collector-Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | -50 | V |
| Collector-Emitter Voltage | $\mathrm{V}_{\mathrm{CEO}}$ | -50 | V |
| Emitter-Base Voltage | $\mathrm{V}_{\mathrm{EBO}}$ | -5 | V |
| Collector Current | $\mathrm{I}_{\mathrm{C}}$ | -150 | mA |
| Base Current | $\mathrm{I}_{\mathrm{B}}$ | -50 | mA |
| Collector Power Dissipation | $\mathrm{P}_{\mathrm{C}}$ | 400 | mW |
| Junction Temperature | $\mathrm{T}_{\mathrm{j}}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | $-55 \sim 125$ | ${ }^{\circ} \mathrm{C}$ |



Weight : 0.21 g

## ELECTRICAL CHARACTERISTICS $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| Collector Cut-off Current | $\mathrm{I}_{\mathrm{CBO}}$ | $\mathrm{V}_{\mathrm{CB}}=-50 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$ | - | - | -0.1 | $\mu \mathrm{~A}$ |
| Emitter Cut-off Current | $\mathrm{I}_{\mathrm{EBO}}$ | $\mathrm{V}_{\mathrm{EB}}=-5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ | - | - | -0.1 | $\mu \mathrm{~A}$ |
| DC Current Gain | $\mathrm{h}_{\mathrm{FE}}(1)(\mathrm{Note})$ | $\mathrm{V}_{\mathrm{CE}}=-6 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-2 \mathrm{~mA}$ | 70 | - | 400 |  |
|  | $\mathrm{~h}_{\mathrm{FE}}(2)$ | $\mathrm{V}_{\mathrm{CE}}=-6 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-150 \mathrm{~mA}$ | 25 | 80 | - |  |
| Collector-Emitter <br> Saturation Voltage | $\mathrm{V}_{\mathrm{CE}}(\mathrm{sat})$ | $\mathrm{I}_{\mathrm{C}}=-100 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-10 \mathrm{~mA}$ | - | -0.1 | -0.3 | V |
| Base-Emitter <br> Saturation Voltage | $\mathrm{V}_{\mathrm{BE}}(\mathrm{sat})$ | $\mathrm{I}_{\mathrm{C}}=-100 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=-10 \mathrm{~mA}$ | - | - | -1.1 | V |
| Transition Frequency | $\mathrm{f}_{\mathrm{T}}$ | $\mathrm{V}_{\mathrm{CE}}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-1 \mathrm{~mA}$ | 80 | - | - | MHz |
| Collector Output Capacitance | $\mathrm{C}_{\mathrm{ob}}$ | $\mathrm{V}_{\mathrm{CB}}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$, <br> $\mathrm{f}=1 \mathrm{MHz}$ | - | 4 | 7 | pF |
| Base Intrinsic Resistance | $\mathrm{r}_{\mathrm{bb}}$, | $\mathrm{V}_{\mathrm{CE}}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=1 \mathrm{~mA}$, <br> $\mathrm{f}=30 \mathrm{MHz}$ | - | 30 | - | $\Omega$ |
| Noise Figure | NF | $\mathrm{V}_{\mathrm{CE}}=-6 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=-0.1 \mathrm{~mA}$, <br> $\mathrm{R}_{\mathrm{G}}=10 \mathrm{k} \Omega, \mathrm{f}=1 \mathrm{kHz}$ | - | 1.0 | 10 | dB |

Note : hFE (1) Classification $\quad \mathrm{O}: 70 \sim 140, \mathrm{Y}: 120 \sim 240, \quad$ GR $: 200 \sim 400$


